

- ☛ S333: (2) "2064014048"
- ☛ S334: (55) amorphous adj. Si adj. TFT
- ☛ S335: (245623) amorphous
- ☛ S336: (3) amorphous adj. Si adj. buffer
- ☛ S337: (55204) amorphous adj. silicon
- ☛ S338: (7492) amorphous adj. Si
- ☛ S339: (34374) Buffer used layer
- ☛ S340: (01) S338 near S339
- ☛ S341: (253) S338 and S339
- ☛ S342: (44) S341 and TFT
- ☛ S343: (55) S337 near buffer
- ☛ S344: (07) S343 and TFT
- ☛ S345: (62) amorphous adj. buffer adj. layer
- ☛ S347: (0) S346 and TFT
- ☛ S348: (74) amorphous adj. buffer
- ☛ S348: (0) "6531716" PPN.
- ☛ S349: (972) S337 and TFT and (buffer adj. layer)
- ☛ S350: (33526) Buffer adj. layer
- ☛ S351: (48484) fluo adj. fluo adj. transistor
- ☛ S352: (0) S345 and S351
- ☛ S353: (01) S345 and TFT
- ☛ S354: (0023) S337 and S350 and S351
- ☛ S355: (1023) S354 and S350
- ☛ S356: (4543) SiO₂ adj. layer
- ☛ S357: (6) S355 and S356
- ☛ S358: (3219529) amorphous near layer
- ☛ S359: (17738) amorphous near layer
- ☛ S360: (056) S359 and S356
- ☛ S361: (19) S360 and TFT
- ☛ S362: (4669) S337 with TFT
- ☛ S363: (404) S359 and S362
- ☛ S364: (4669) S337 with TFT
- ☛ S365: (1046) S337 near TFT
- ☛ S366: (32) S365 and (buffer adj. layer)

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	1	2	Document ID	Issue Date	Pages	Title	Current OR	Current XRef	Retrieval Cla	Inventor	S	C	P	Image 1*	
1	<input type="checkbox"/>	<input type="checkbox"/>	US 6566180 B2	20050526	24	Thin film transistor and fabrication method thereof	438/166	438/163		Park; Kee-Chan et al.	<input checked="" type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 6566
2	<input type="checkbox"/>	<input type="checkbox"/>	US 6455874 B1	20020824	24	Thin film transistor and fabrication method thereof	257/63	257/147		Park; Kee-Chan et al.	<input checked="" type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 6455